

December 1992

### Features

- High Voltage Type (20V Rating)
- 3-State Parallel Outputs for Connection to Common Bus
- Separate Serial Outputs Synchronous to Both Positive and Negative Clock Edges for Cascading
- Medium Speed Operation - 5MHz at 10V (typ)
- Standardized Symmetrical Output Characteristics
- 100% Tested for Quiescent Current at 20V
- Maximum Input Current of 1 $\mu$ A at 18V Over Full Package Temperature Range; 100nA at 18V and +25°C
- Noise Margin (Over Full Package/Temperature Range)
  - 1V at VDD = 5V
  - 2V at VDD = 10V
  - 2.5V at VDD = 15V
- 5V, 10V and 15V Parametric Ratings
- Meets All Requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

### Applications

- Serial-to-Parallel Data Conversion
- Remote Control Holding Register
- Dual-Rank Shift, Hold, and Bus Applications

### Description

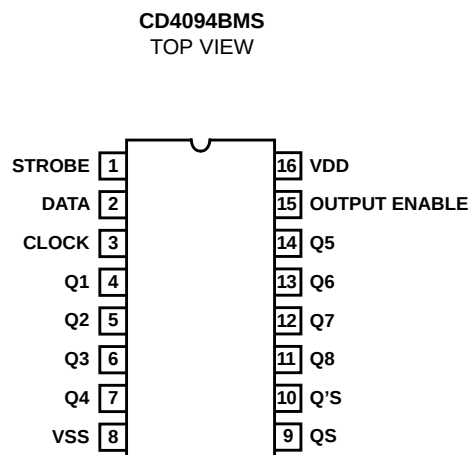
CD4094BMS is a 8-stage serial shift register having a storage latch associated with each stage for strobing data from the serial input to parallel buffered 3-state outputs. The parallel outputs may be connected directly to common bus lines. Data is shifted on positive clock transitions. The data in each shift register stage is transferred to the storage register when the STROBE input is high. Data in the storage register appears at the outputs whenever the OUTPUT-ENABLE signal is high.

Two serial outputs are available for cascading a number of CD4094BMS devices. Data is available at the QS serial output terminal on positive clock edges to allow for high-speed operation in cascaded systems in which the clock rise time is fast. The same serial information, available at the Q'S terminal on the next negative clock edge, provides a means for cascading CD4094BMS devices when the clock rise time is slow.

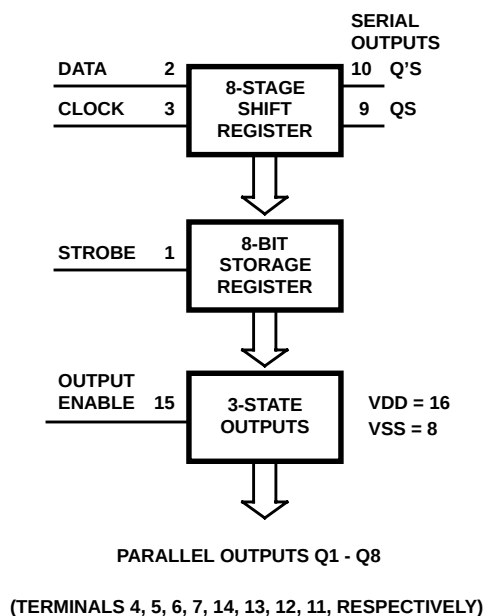
The CD4094BMS is supplied in these 16 lead outline packages:

|                  |     |
|------------------|-----|
| Braze Seal DIP   | H4X |
| Frit Seal DIP    | H1F |
| Ceramic Flatpack | H6W |

### Pinout



### Functional Diagram



## Specifications CD4094BMS

### Absolute Maximum Ratings

DC Supply Voltage Range, (VDD) ..... -0.5V to +20V  
 (Voltage Referenced to VSS Terminals)  
 Input Voltage Range, All Inputs ..... -0.5V to VDD +0.5V  
 DC Input Current, Any One Input .....  $\pm 10\mu\text{A}$   
 Operating Temperature Range ..... -55°C to +125°C  
 Package Types D, F, K, H  
 Storage Temperature Range (TSTG) ..... -65°C to +150°C  
 Lead Temperature (During Soldering) ..... +265°C  
 At Distance 1/16  $\pm$  1/32 Inch (1.59mm  $\pm$  0.79mm) from case for  
 10s Maximum

### Reliability Information

Thermal Resistance .....  $\theta_{ja}$   $\theta_{jc}$   
 Ceramic DIP and FRIT Package ..... 80°C/W 20°C/W  
 Flatpack Package ..... 70°C/W 20°C/W  
 Maximum Package Power Dissipation (PD) at +125°C  
 For TA = -55°C to +100°C (Package Type D, F, K) ..... 500mW  
 For TA = +100°C to +125°C (Package Type D, F, K) ..... Derate  
 Linearity at 12mW/°C to 200mW  
 Device Dissipation per Output Transistor ..... 100mW  
 For TA = Full Package Temperature Range (All Package Types)  
 Junction Temperature ..... +175°C

**TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS**

| PARAMETER                      | SYMBOL | CONDITIONS (NOTE 1)                   |           | GROUP A<br>SUBGROUPS | TEMPERATURE          | LIMITS         |                | UNITS         |
|--------------------------------|--------|---------------------------------------|-----------|----------------------|----------------------|----------------|----------------|---------------|
|                                |        |                                       |           |                      |                      | MIN            | MAX            |               |
| Supply Current                 | IDD    | VDD = 20V, VIN = VDD or GND           |           | 1                    | +25°C                | -              | 10             | $\mu\text{A}$ |
|                                |        |                                       |           | 2                    | +125°C               | -              | 1000           | $\mu\text{A}$ |
|                                |        | VDD = 18V, VIN = VDD or GND           |           | 3                    | -55°C                | -              | 10             | $\mu\text{A}$ |
| Input Leakage Current          | IIL    | VIN = VDD or GND                      | VDD = 20  | 1                    | +25°C                | -100           | -              | nA            |
|                                |        |                                       |           | 2                    | +125°C               | -1000          | -              | nA            |
|                                |        |                                       | VDD = 18V | 3                    | -55°C                | -100           | -              | nA            |
| Input Leakage Current          | IIH    | VIN = VDD or GND                      | VDD = 20  | 1                    | +25°C                | -              | 100            | nA            |
|                                |        |                                       |           | 2                    | +125°C               | -              | 1000           | nA            |
|                                |        |                                       | VDD = 18V | 3                    | -55°C                | -              | 100            | nA            |
| Output Voltage                 | VOL15  | VDD = 15V, No Load                    |           | 1, 2, 3              | +25°C, +125°C, -55°C | -              | 50             | mV            |
| Output Voltage                 | VOH15  | VDD = 15V, No Load (Note 3)           |           | 1, 2, 3              | +25°C, +125°C, -55°C | 14.95          | -              | V             |
| Output Current (Sink)          | IOL5   | VDD = 5V, VOUT = 0.4V                 |           | 1                    | +25°C                | 0.53           | -              | mA            |
| Output Current (Sink)          | IOL10  | VDD = 10V, VOUT = 0.5V                |           | 1                    | +25°C                | 1.4            | -              | mA            |
| Output Current (Sink)          | IOL15  | VDD = 15V, VOUT = 1.5V                |           | 1                    | +25°C                | 3.5            | -              | mA            |
| Output Current (Source)        | IOH5A  | VDD = 5V, VOUT = 4.6V                 |           | 1                    | +25°C                | -              | -0.53          | mA            |
| Output Current (Source)        | IOH5B  | VDD = 5V, VOUT = 2.5V                 |           | 1                    | +25°C                | -              | -1.8           | mA            |
| Output Current (Source)        | IOH10  | VDD = 10V, VOUT = 9.5V                |           | 1                    | +25°C                | -              | -1.4           | mA            |
| Output Current (Source)        | IOH15  | VDD = 15V, VOUT = 13.5V               |           | 1                    | +25°C                | -              | -3.5           | mA            |
| N Threshold Voltage            | VNTH   | VDD = 10V, ISS = -10 $\mu\text{A}$    |           | 1                    | +25°C                | -2.8           | -0.7           | V             |
| P Threshold Voltage            | VPTH   | VSS = 0V, IDD = 10 $\mu\text{A}$      |           | 1                    | +25°C                | 0.7            | 2.8            | V             |
| Functional                     | F      | VDD = 2.8V, VIN = VDD or GND          |           | 7                    | +25°C                | VOH ><br>VDD/2 | VOL <<br>VDD/2 | V             |
|                                |        | VDD = 20V, VIN = VDD or GND           |           | 7                    | +25°C                |                |                |               |
|                                |        | VDD = 18V, VIN = VDD or GND           |           | 8A                   | +125°C               |                |                |               |
|                                |        | VDD = 3V, VIN = VDD or GND            |           | 8B                   | -55°C                |                |                |               |
| Input Voltage Low<br>(Note 2)  | VIL    | VDD = 5V, VOH > 4.5V, VOL < 0.5V      |           | 1, 2, 3              | +25°C, +125°C, -55°C | -              | 1.5            | V             |
| Input Voltage High<br>(Note 2) | VIH    | VDD = 5V, VOH > 4.5V, VOL < 0.5V      |           | 1, 2, 3              | +25°C, +125°C, -55°C | 3.5            | -              | V             |
| Input Voltage Low<br>(Note 2)  | VIL    | VDD = 15V, VOH > 13.5V,<br>VOL < 1.5V |           | 1, 2, 3              | +25°C, +125°C, -55°C | -              | 4              | V             |
| Input Voltage High<br>(Note 2) | VIH    | VDD = 15V, VOH > 13.5V,<br>VOL < 1.5V |           | 1, 2, 3              | +25°C, +125°C, -55°C | 11             | -              | V             |
| Tri-State Output<br>Leakage    | IOZL   | VIN = VDD or GND<br>VOUT = 0V         | VDD = 20V | 1                    | +25°C                | -0.4           | -              | $\mu\text{A}$ |
|                                |        |                                       |           | 2                    | +125°C               | -12            | -              | $\mu\text{A}$ |
|                                |        |                                       | VDD = 18V | 3                    | -55°C                | -0.4           | -              | $\mu\text{A}$ |
| Tri-State Output<br>Leakage    | IOZH   | VIN = VDD or GND<br>VOUT = VDD        | VDD = 20V | 1                    | +25°C                | -              | 0.4            | $\mu\text{A}$ |
|                                |        |                                       |           | 2                    | +125°C               | -              | 12             | $\mu\text{A}$ |
|                                |        |                                       | VDD = 18V | 3                    | -55°C                | -              | 0.4            | $\mu\text{A}$ |

NOTES: 1. All voltages referenced to device GND, 100% testing being implemented. 3. For accuracy, voltage is measured differentially to VDD. Limit is 0.050V max.  
 2. Go/No Go test with limits applied to inputs.

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**TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS**

| PARAMETER                                                | SYMBOL         | CONDITIONS                                | GROUP A<br>SUBGROUPS | TEMPERATURE   | LIMITS |      | UNITS |
|----------------------------------------------------------|----------------|-------------------------------------------|----------------------|---------------|--------|------|-------|
|                                                          |                |                                           |                      |               | MIN    | MAX  |       |
| Propagation Delay<br>Clock to Serial Output QS           | TPHL1<br>TPLH1 | VDD = 5V, VIN = VDD or GND<br>(Note 1, 2) | 9                    | +25°C         | -      | 600  | ns    |
|                                                          |                |                                           | 10, 11               | +125°C, -55°C | -      | 810  | ns    |
| Propagation Delay<br>Clock to Serial Output Q'S          | TPHL2<br>TPLH2 | VDD = 5V, VIN = VDD or GND<br>(Note 1, 2) | 9                    | +25°C         | -      | 460  | ns    |
|                                                          |                |                                           | 10, 11               | +125°C, -55°C | -      | 621  | ns    |
| Propagation Delay<br>Clock to Parallel Output            | TPHL3<br>TPLH3 | VDD = 5V, VIN = VDD or GND<br>(Note 1, 2) | 9                    | +25°C         | -      | 840  | ns    |
|                                                          |                |                                           | 10, 11               | +125°C, -55°C | -      | 1134 | ns    |
| Propagation Delay<br>Strobe to Parallel Output           | TPHL4<br>TPLH4 | VDD = 5V, VIN = VDD or GND<br>(Note 1, 2) | 9                    | +25°C         | -      | 580  | ns    |
|                                                          |                |                                           | 10, 11               | +125°C, -55°C | -      | 783  | ns    |
| Propagation Delay<br>Output Enable to Parallel<br>Output | TPHZ<br>TPZH   | VDD = 5V, VIN = VDD or GND<br>(Note 2, 3) | 9                    | +25°C         | -      | 280  | ns    |
|                                                          |                |                                           | 10, 11               | +125°C, -55°C | -      | 378  | ns    |
| Propagation Delay<br>Output Enable to Parallel<br>Output | TPLZ<br>TPZL   | VDD = 5V, VIN = VDD or GND<br>(Note 2, 3) | 9                    | +25°C         | -      | 200  | ns    |
|                                                          |                |                                           | 10, 11               | +125°C, -55°C | -      | 270  | ns    |
| Transition Time                                          | TTHL<br>TTLH   | VDD = 5V, VIN = VDD or GND<br>(Note 1, 2) | 9                    | +25°C         | -      | 200  | ns    |
|                                                          |                |                                           | 10, 11               | +125°C, -55°C | -      | 270  | ns    |
| Maximum Clock Input<br>Frequency                         | FCL            | VDD = 5V, VIN = VDD or GND<br>(Note 1, 2) | 9                    | +25°C         | 1.25   | -    | MHz   |
|                                                          |                |                                           | 10, 11               | +125°C, -55°C | .93    | -    | MHz   |

**NOTES:**

1. CL = 50pF, RL = 200K, Input TR, TF < 20ns.
2. -55°C and +125°C limits guaranteed, 100% testing being implemented.
3. CL = 50pF, RL = 1K, Input TR, TF < 20ns.

**TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS**

| PARAMETER             | SYMBOL | CONDITIONS                  | NOTES | TEMPERATURE             | LIMITS |     | UNITS |
|-----------------------|--------|-----------------------------|-------|-------------------------|--------|-----|-------|
|                       |        |                             |       |                         | MIN    | MAX |       |
| Supply Current        | IDD    | VDD = 5V, VIN = VDD or GND  | 1, 2  | -55°C, +25°C            | -      | 5   | μA    |
|                       |        |                             |       | +125°C                  | -      | 150 | μA    |
|                       |        | VDD = 10V, VIN = VDD or GND | 1, 2  | -55°C, +25°C            | -      | 10  | μA    |
|                       |        |                             |       | +125°C                  | -      | 300 | μA    |
|                       |        | VDD = 15V, VIN = VDD or GND | 1, 2  | -55°C, +25°C            | -      | 10  | μA    |
|                       |        |                             |       | +125°C                  | -      | 600 | μA    |
| Output Voltage        | VOL    | VDD = 5V, No Load           | 1, 2  | +25°C, +125°C,<br>-55°C | -      | 50  | mV    |
| Output Voltage        | VOL    | VDD = 10V, No Load          | 1, 2  | +25°C, +125°C,<br>-55°C | -      | 50  | mV    |
| Output Voltage        | VOH    | VDD = 5V, No Load           | 1, 2  | +25°C, +125°C,<br>-55°C | 4.95   | -   | V     |
| Output Voltage        | VOH    | VDD = 10V, No Load          | 1, 2  | +25°C, +125°C,<br>-55°C | 9.95   | -   | V     |
| Output Current (Sink) | IOL5   | VDD = 5V, VOUT = 0.4V       | 1, 2  | +125°C                  | 0.36   | -   | mA    |
|                       |        |                             |       | -55°C                   | 0.64   | -   | mA    |
| Output Current (Sink) | IOL10  | VDD = 10V, VOUT = 0.5V      | 1, 2  | +125°C                  | 0.9    | -   | mA    |
|                       |        |                             |       | -55°C                   | 1.6    | -   | mA    |

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**TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)**

| PARAMETER                                                | SYMBOL         | CONDITIONS                    | NOTES      | TEMPERATURE          | LIMITS |       | UNITS |
|----------------------------------------------------------|----------------|-------------------------------|------------|----------------------|--------|-------|-------|
|                                                          |                |                               |            |                      | MIN    | MAX   |       |
| Output Current (Sink)                                    | IOL15          | VDD = 15V, VOUT = 1.5V        | 1, 2       | +125°C               | 2.4    | -     | mA    |
|                                                          |                |                               |            | -55°C                | 4.2    | -     | mA    |
| Output Current (Source)                                  | IOH5A          | VDD = 5V, VOUT = 4.6V         | 1, 2       | +125°C               | -      | -0.36 | mA    |
|                                                          |                |                               |            | -55°C                | -      | -0.64 | mA    |
| Output Current (Source)                                  | IOH5B          | VDD = 5V, VOUT = 2.5V         | 1, 2       | +125°C               | -      | -1.1  | mA    |
|                                                          |                |                               |            | -55°C                | -      | -2.0  | mA    |
| Output Current (Source)                                  | IOH10          | VDD = 10V, VOUT = 9.5V        | 1, 2       | +125°C               | -      | -0.9  | mA    |
|                                                          |                |                               |            | -55°C                | -      | -2.6  | mA    |
| Output Current (Source)                                  | IOH15          | VDD = 15V, VOUT = 13.5V       | 1, 2       | +125°C               | -      | -2.4  | mA    |
|                                                          |                |                               |            | -55°C                | -      | -     | mA    |
| Input Voltage Low                                        | VIL            | VDD = 10V, VOH > 9V, VOL < 1V | 1, 2       | +25°C, +125°C, -55°C | -      | 3     | V     |
| Input Voltage High                                       | VIH            | VDD = 10V, VOH > 9V, VOL < 1V | 1, 2       | +25°C, +125°C, -55°C | 7      | -     | V     |
| Propagation Delay<br>Clock to Serial Output Qs           | TPHL1<br>TPLH1 | VDD = 10V                     | 1, 2, 3    | +25°C                | -      | 250   | ns    |
|                                                          |                | VDD = 15V                     | 1, 2, 3    | +25°C                | -      | 190   | ns    |
| Propagation Delay<br>Clock to Serial Output Q's          | TPHL2<br>TPLH2 | VDD = 10V                     | 1, 2, 3    | +25°C                | -      | 220   | ns    |
|                                                          |                | VDD = 15V                     | 1, 2, 3    | +25°C                | -      | 150   | ns    |
| Propagation Delay<br>Clock to Parallel Output            | TPHL3<br>TPLH3 | VDD = 10V                     | 1, 2, 3    | +25°C                | -      | 390   | ns    |
|                                                          |                | VDD = 15V                     | 1, 2, 3    | +25°C                | -      | 270   | ns    |
| Propagation Delay<br>Strobe to Parallel Output           | TPHL4<br>TPLH4 | VDD = 10V                     | 1, 2, 3    | +25°C                | -      | 290   | ns    |
|                                                          |                | VDD = 15V                     | 1, 2, 3    | +25°C                | -      | 200   | ns    |
| Propagation Delay<br>Output Enable to Parallel<br>Output | TPHZ<br>TPZH   | VDD = 10V                     | 1, 2, 4    | +25°C                | -      | 120   | ns    |
|                                                          |                | VDD = 15V                     | 1, 2, 4    | +25°C                | -      | 90    | ns    |
| Propagation Delay<br>Output Enable to Parallel<br>Output | TPLZ<br>TPZL   | VDD = 10V                     | 1, 2, 4    | +25°C                | -      | 100   | ns    |
|                                                          |                | VDD = 15V                     | 1, 2, 4    | +25°C                | -      | 80    | ns    |
| Transition Time                                          | TTLH<br>TTHL   | VDD = 10V                     | 1, 2, 3    | +25°C                | -      | 100   | ns    |
|                                                          |                | VDD = 15V                     | 1, 2, 3    | +25°C                | -      | 80    | ns    |
| Maximum Clock Input<br>Frequency                         | FCL            | VDD = 10V                     | 1, 2, 3    | +25°C                | 2.5    | -     | MHz   |
|                                                          |                | VDD = 15V                     | 1, 2, 3    | +25°C                | 3      | -     | MHz   |
| Minimum Data Setup<br>Time                               | TS             | VDD = 5V                      | 1, 2, 3    | +25°C                | -      | 125   | ns    |
|                                                          |                | VDD = 10V                     | 1, 2, 3    | +25°C                | -      | 55    | ns    |
|                                                          |                | VDD = 15V                     | 1, 2, 3    | +25°C                | -      | 35    | ns    |
| Maximum Clock Input<br>Rise and Fall Time                | TRCL<br>TFCL   | VDD = 5V                      | 1, 2, 3, 5 | +25°C                | -      | 15    | μs    |
|                                                          |                | VDD = 10V                     | 1, 2, 3, 5 | +25°C                | -      | 5     | μs    |
|                                                          |                | VDD = 15V                     | 1, 2, 3, 5 | +25°C                | -      | 5     | μs    |
| Minimum Clock Pulse<br>Width                             | TW             | VDD = 5V                      | 1, 2, 3    | +25°C                | -      | 200   | ns    |
|                                                          |                | VDD = 10V                     | 1, 2, 3    | +25°C                | -      | 100   | ns    |
|                                                          |                | VDD = 15V                     | 1, 2, 3    | +25°C                | -      | 83    | ns    |

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**TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)**

| PARAMETER                  | SYMBOL | CONDITIONS | NOTES   | TEMPERATURE | LIMITS |     | UNITS |
|----------------------------|--------|------------|---------|-------------|--------|-----|-------|
|                            |        |            |         |             | MIN    | MAX |       |
| Minimum Strobe Pulse Width | TW     | VDD = 5V   | 1, 2, 3 | +25°C       | -      | 200 | ns    |
|                            |        | VDD = 10V  | 1, 2, 3 | +25°C       | -      | 80  | ns    |
|                            |        | VDD = 15V  | 1, 2, 3 | +25°C       | -      | 70  | ns    |
| Input Capacitance          | CIN    | Any Input  | 1, 2    | +25°C       | -      | 7.5 | pF    |

**NOTES:**

1. All voltages referenced to device GND.
2. The parameters listed on Table 3 are controlled via design or process and are not directly tested. These parameters are characterized on initial design release and upon design changes which would affect these characteristics.
3. CL = 50pF, RL = 200K, Input TR, TF < 20ns.
4. CL = 50pF, RL = 1K, Input TR, TF < 20ns.
5. If more than one unit is cascaded, TRCL should be made less than or equal to the sum of the transition time and the fixed propagation delay of the output of the driving stage for the estimated capacitive load.

**TABLE 4. POST IRRADIATION ELECTRICAL PERFORMANCE CHARACTERISTICS**

| PARAMETER                 | SYMBOL       | CONDITIONS                  | NOTES      | TEMPERATURE | LIMITS      |                    | UNITS |
|---------------------------|--------------|-----------------------------|------------|-------------|-------------|--------------------|-------|
|                           |              |                             |            |             | MIN         | MAX                |       |
| Supply Current            | IDD          | VDD = 20V, VIN = VDD or GND | 1, 4       | +25°C       | -           | 25                 | μA    |
| N Threshold Voltage       | VNTH         | VDD = 10V, ISS = -10μA      | 1, 4       | +25°C       | -2.8        | -0.2               | V     |
| N Threshold Voltage Delta | ΔVTN         | VDD = 10V, ISS = -10μA      | 1, 4       | +25°C       | -           | ±1                 | V     |
| P Threshold Voltage       | VTP          | VSS = 0V, IDD = 10μA        | 1, 4       | +25°C       | 0.2         | 2.8                | V     |
| P Threshold Voltage Delta | ΔVTP         | VSS = 0V, IDD = 10μA        | 1, 4       | +25°C       | -           | ±1                 | V     |
| Functional                | F            | VDD = 18V, VIN = VDD or GND | 1          | +25°C       | VOH > VDD/2 | VOL < VDD/2        | V     |
|                           |              | VDD = 3V, VIN = VDD or GND  |            |             |             |                    |       |
| Propagation Delay Time    | TPHL<br>TPLH | VDD = 5V                    | 1, 2, 3, 4 | +25°C       | -           | 1.35 x +25°C Limit | ns    |

- NOTES: 1. All voltages referenced to device GND. 3. See Table 2 for +25°C limit.  
2. CL = 50pF, RL = 200K, Input TR, TF < 20ns. 4. Read and Record

**TABLE 5. BURN-IN AND LIFE TEST DELTA PARAMETERS +25°C**

| PARAMETER               | SYMBOL | DELTA LIMIT              |
|-------------------------|--------|--------------------------|
| Supply Current - MSI-2  | IDD    | ± 1.0μA                  |
| Output Current (Sink)   | IOL5   | ± 20% x Pre-Test Reading |
| Output Current (Source) | IOH5A  | ± 20% x Pre-Test Reading |

**TABLE 6. APPLICABLE SUBGROUPS**

| CONFORMANCE GROUP          | MIL-STD-883 METHOD | GROUP A SUBGROUPS | READ AND RECORD  |
|----------------------------|--------------------|-------------------|------------------|
| Initial Test (Pre Burn-In) | 100% 5004          | 1, 7, 9           | IDD, IOL5, IOH5A |

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**TABLE 6. APPLICABLE SUBGROUPS**

| CONFORMANCE GROUP             |              | MIL-STD-883 METHOD | GROUP A SUBGROUPS                     | READ AND RECORD              |
|-------------------------------|--------------|--------------------|---------------------------------------|------------------------------|
| Interim Test 1 (Post Burn-In) |              | 100% 5004          | 1, 7, 9                               | IDD, IOL5, IOH5A             |
| Interim Test 2 (Post Burn-In) |              | 100% 5004          | 1, 7, 9                               | IDD, IOL5, IOH5A             |
| PDA (Note 1)                  |              | 100% 5004          | 1, 7, 9, Deltas                       |                              |
| Interim Test 3 (Post Burn-In) |              | 100% 5004          | 1, 7, 9                               | IDD, IOL5, IOH5A             |
| PDA (Note 1)                  |              | 100% 5004          | 1, 7, 9, Deltas                       |                              |
| Final Test                    |              | 100% 5004          | 2, 3, 8A, 8B, 10, 11                  |                              |
| Group A                       |              | Sample 5005        | 1, 2, 3, 7, 8A, 8B, 9, 10, 11         |                              |
| Group B                       | Subgroup B-5 | Sample 5005        | 1, 2, 3, 7, 8A, 8B, 9, 10, 11, Deltas | Subgroups 1, 2, 3, 9, 10, 11 |
|                               | Subgroup B-6 | Sample 5005        | 1, 7, 9                               |                              |
| Group D                       |              | Sample 5005        | 1, 2, 3, 8A, 8B, 9                    | Subgroups 1, 2 3             |

NOTE: 1. 5% Parametric, 3% Functional; Cumulative for Static 1 and 2.

**TABLE 7. TOTAL DOSE IRRADIATION**

| CONFORMANCE GROUPS | MIL-STD-883 METHOD | TEST      |            | READ AND RECORD |            |
|--------------------|--------------------|-----------|------------|-----------------|------------|
|                    |                    | PRE-IRRAD | POST-IRRAD | PRE-IRRAD       | POST-IRRAD |
| Group E Subgroup 2 | 5005               | 1, 7, 9   | Table 4    | 1, 9            | Table 4    |

**TABLE 8. BURN-IN AND IRRADIATION TEST CONNECTIONS**

| FUNCTION                  | OPEN          | GROUND       | VDD           | 9V $\pm$ -0.5V | OSCILLATOR |       |
|---------------------------|---------------|--------------|---------------|----------------|------------|-------|
|                           |               |              |               |                | 50kHz      | 25kHz |
| Static Burn-In 1 (Note 1) | 4 - 7, 9 - 14 | 1 - 3, 8, 15 | 16            |                |            |       |
| Static Burn-In 2 (Note 1) | 4 - 7, 9 - 14 | 8            | 1 - 3, 15, 16 |                |            |       |
| Dynamic Burn-In (Note 1)  | -             | 8            | 1, 15, 16     | 4 - 7, 9 - 14  | 3          | 2     |
| Irradiation (Note 2)      | 4 - 7, 9 - 14 | 8            | 1 - 3, 15, 16 |                |            |       |

NOTES:

- Each pin except VDD and GND will have a series resistor of  $10K \pm 5\%$ ,  $VDD = 18V \pm 0.5V$
- Each pin except VDD and GND will have a series resistor of  $47K \pm 5\%$ ; Group E, Subgroup 2, sample size is 4 dice/wafer, 0 failures,  $VDD = 10V \pm 0.5V$

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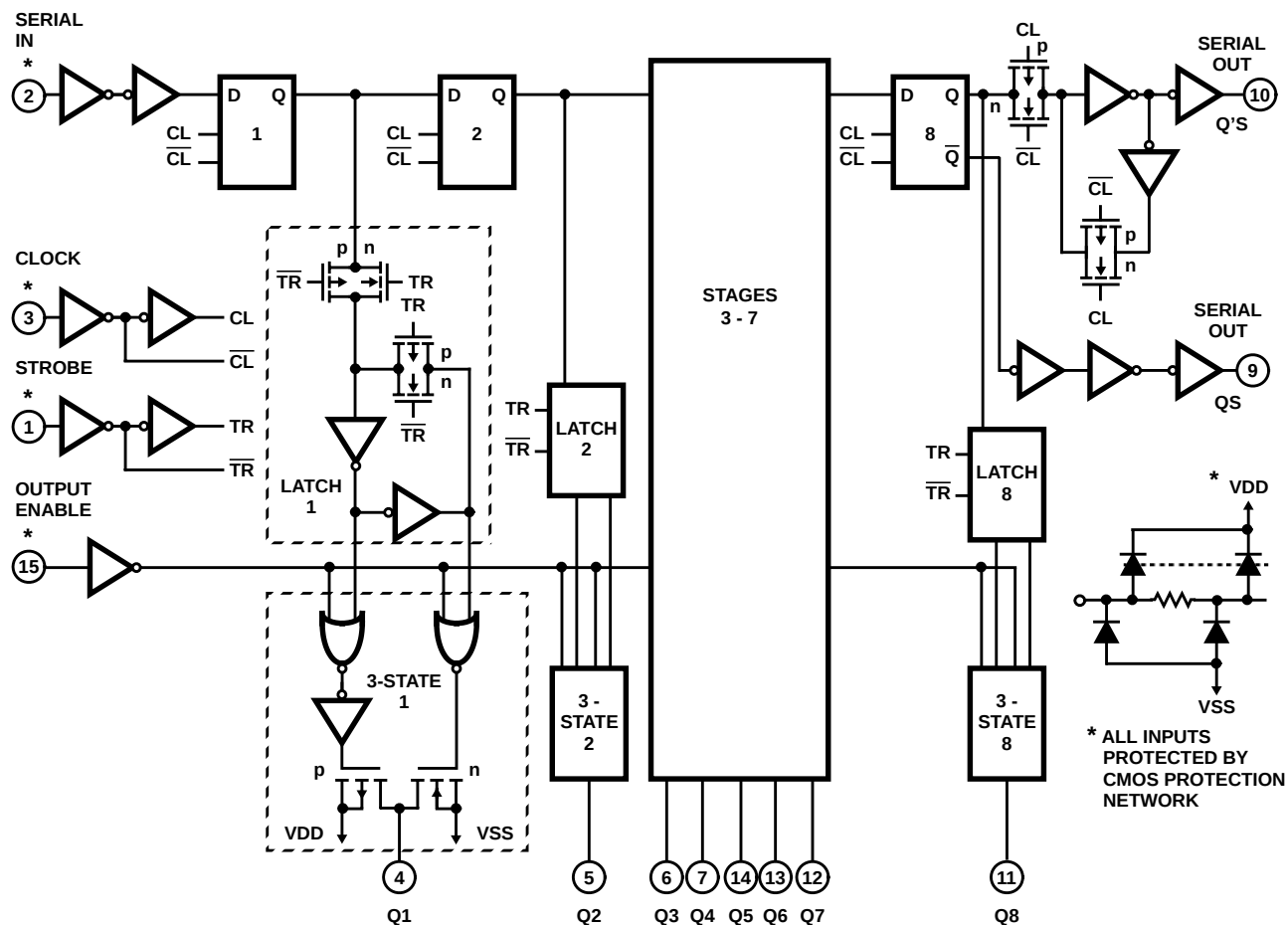


FIGURE 1. LOGIC DIAGRAM

TRUTH TABLE

| CL $\Delta$ | OUTPUT<br>ENABLE | STROBE | DATA | PARALLEL OUTPUTS |      | SERIAL OUTPUTS |     |
|-------------|------------------|--------|------|------------------|------|----------------|-----|
|             |                  |        |      | Q1               | QN   | QS*            | Q'S |
|             | 0                | X      | X    | OC               | OC   | Q7             | NC  |
|             | 0                | X      | X    | OC               | OC   | NC             | Q7  |
|             | 1                | 0      | X    | NC               | NC   | Q7             | NC  |
|             | 1                | 1      | 0    | 0                | QN-1 | Q7             | NC  |
|             | 1                | 1      | 1    | 1                | QN-1 | Q7             | NC  |
|             | 1                | 1      | 1    | NC               | NC   | NC             | Q7  |

$\Delta$  = Level Change

X = Don't Care

NC = No Change

OC = Open Circuit

\* At the positive clock edge information in the 7th shift register stage is transferred to the 8th register stage and the QS output

Logic 1 = High

Logic 0 = Low

## Typical Performance Characteristics

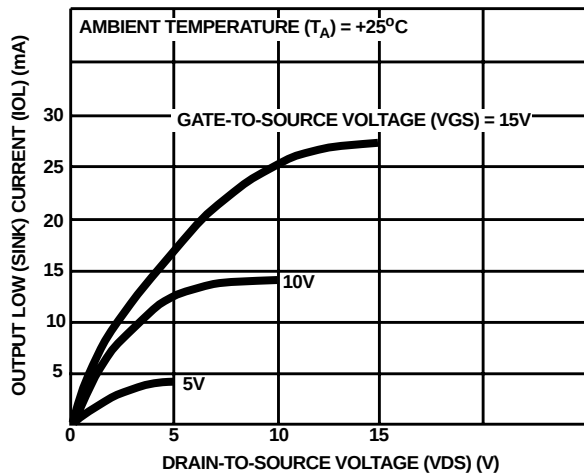


FIGURE 2. TYPICAL OUTPUT LOW (SINK) CURRENT TRANSFER CHARACTERISTICS

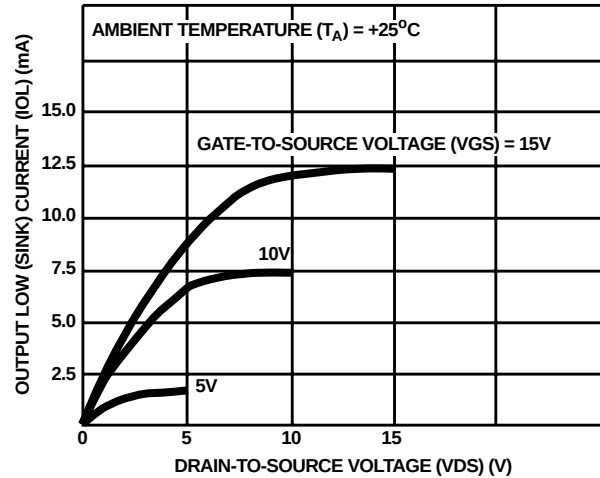


FIGURE 3. MINIMUM OUTPUT LOW (SINK) CURRENT CHARACTERISTICS

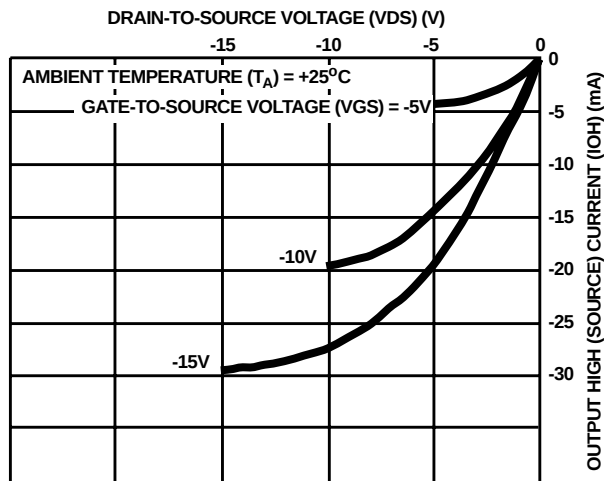


FIGURE 4. TYPICAL OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

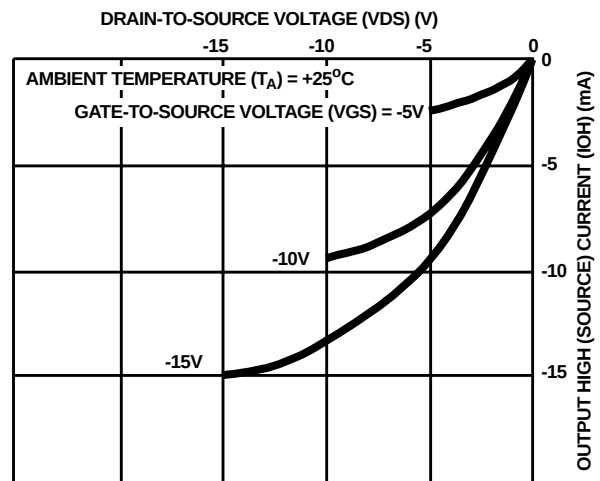


FIGURE 5. MINIMUM OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

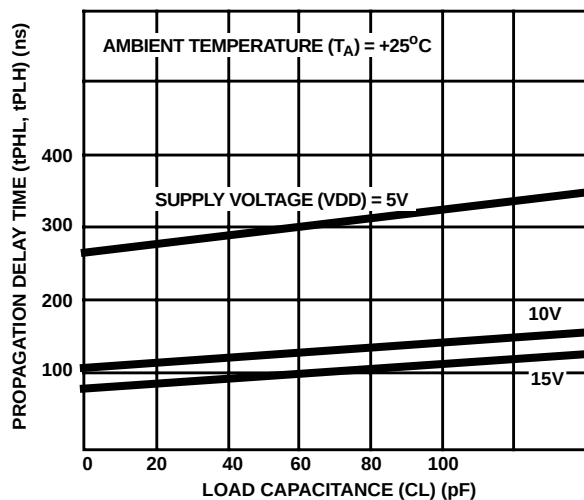


FIGURE 6. CLOCK-TO-SERIAL OUTPUT QS PROPAGATION DELAY vs  $CL$

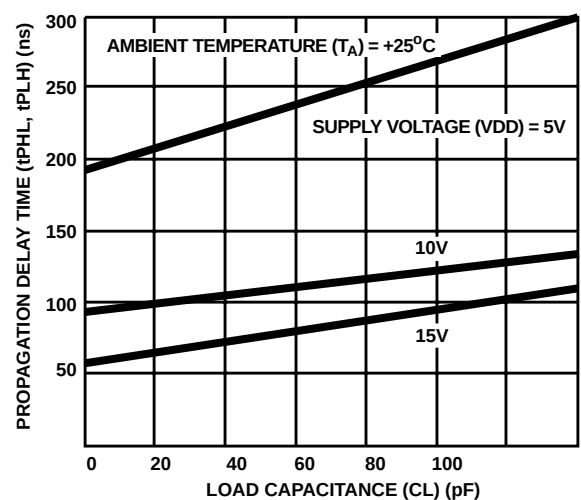


FIGURE 7. CLOCK-TO-SERIAL OUTPUT Q'S PROPAGATION DELAY vs  $CL$

# Typical Performance Characteristics (Continued)

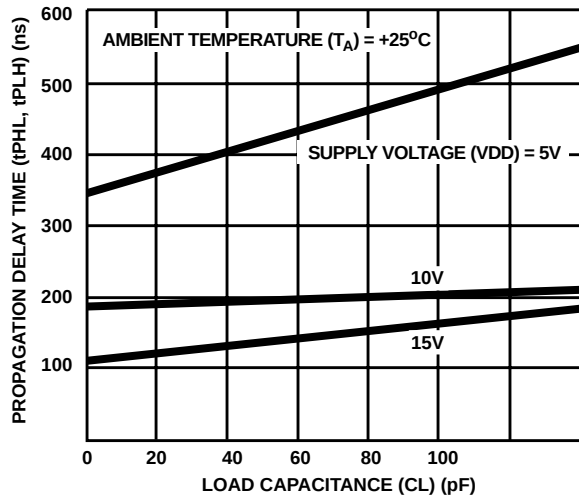


FIGURE 8. CLOCK-TO-PARALLEL OUTPUT PROPAGATION DELAY vs CL

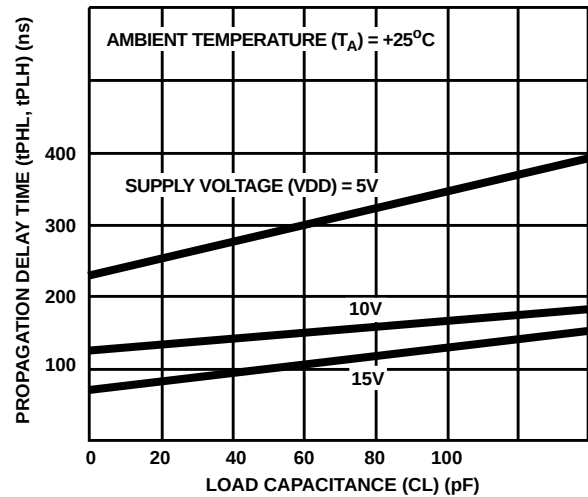


FIGURE 9. STROBE-TO-PARALLEL OUTPUT PROPAGATION DELAY vs CL

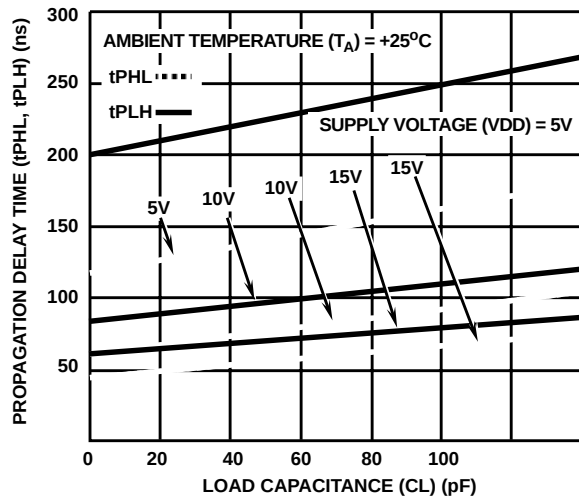


FIGURE 10. OUTPUT ENABLE-TO-PARALLEL OUTPUT PROPAGATION DELAY vs CL

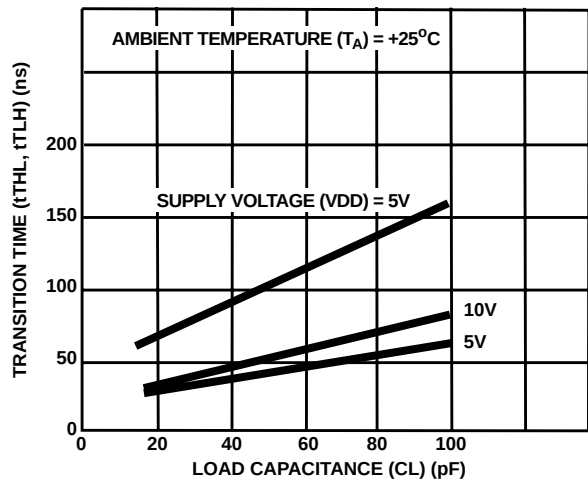


FIGURE 11. TYPICAL TRANSITION TIME vs LOAD CAPACITANCE

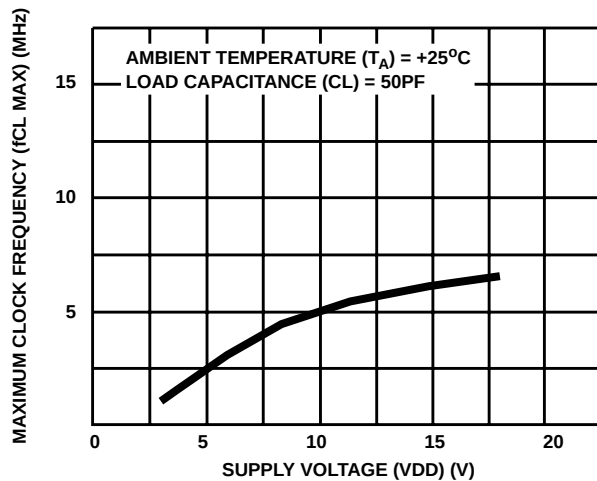


FIGURE 12. TYPICAL MAXIMUM-CLOCK-FREQUENCY vs SUPPLY VOLTAGE

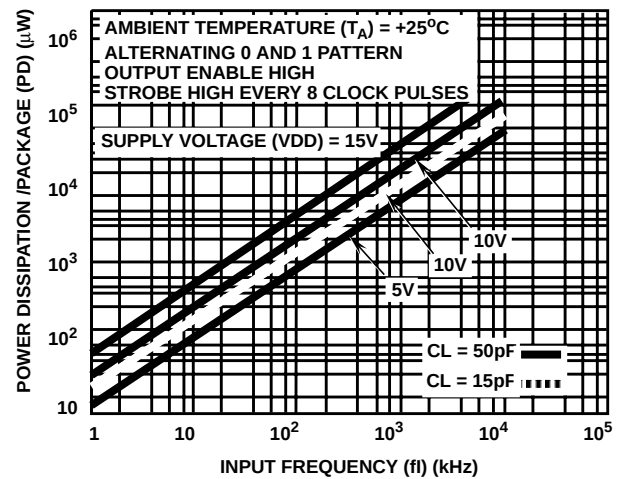


FIGURE 13. DYNAMIC POWER DISSIPATION vs INPUT CLOCK FREQUENCY

# CD4094BMS

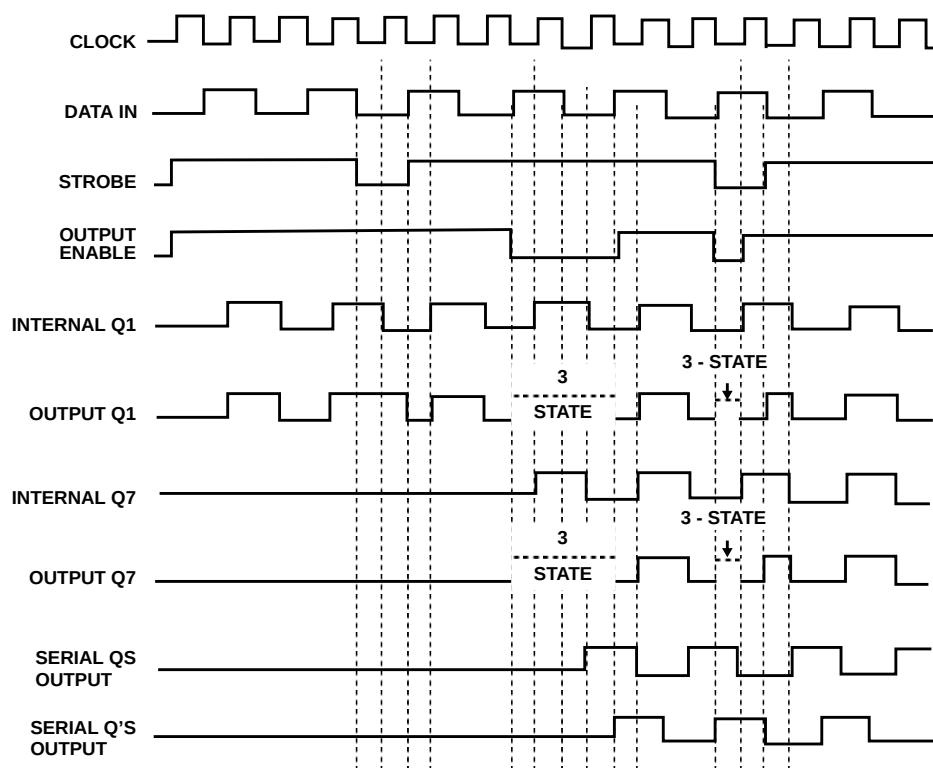


FIGURE 14. TIMING DIAGRAM

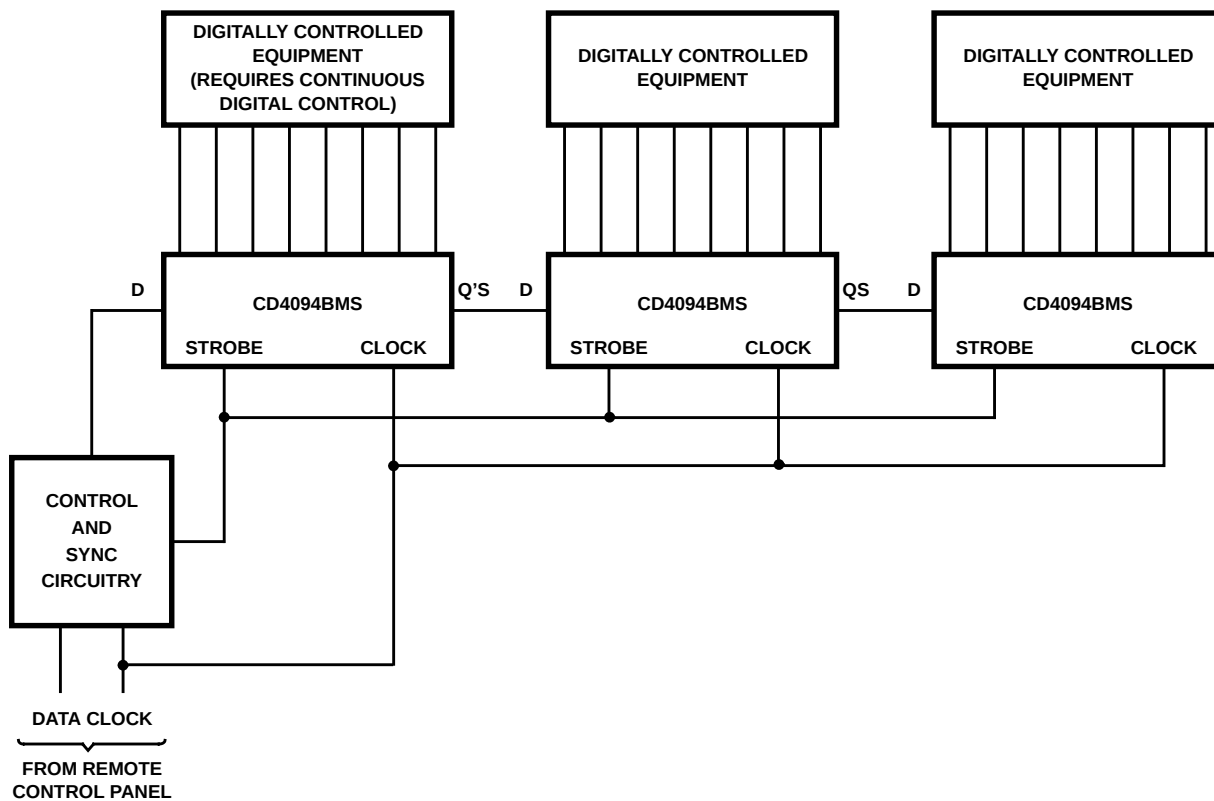
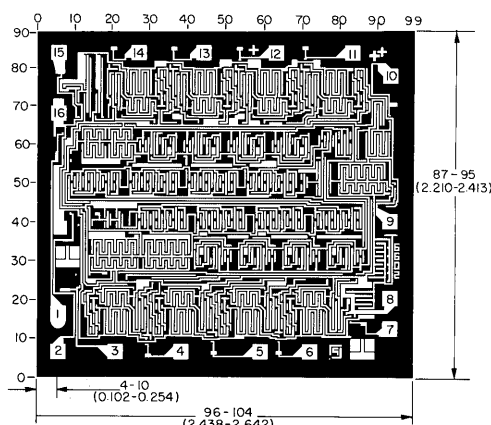


FIGURE 15. REMOTE CONTROL HOLDING REGISTER

## Chip Dimensions and Pad Layout



Dimensions in parenthesis are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils ( $10^{-3}$  inch).

**METALLIZATION:** Thickness:  $11\text{k}\text{\AA}$  –  $14\text{k}\text{\AA}$ , AL.

**PASSIVATION:**  $10.4\text{k}\text{\AA}$  -  $15.6\text{k}\text{\AA}$ , Silane

**BOND PADS:** 0.004 inches X 0.004 inches MIN

**DIE THICKNESS:** 0.0198 inches - 0.0218 inches

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